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PTO/USPTO (08-00)

2811
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MAIL ROOM

TRANSMITTAL FORM <i>(to be used for all correspondence after initial filing)</i>	Application Number	09/210,540
	Filing Date	December 14, 1998
	First Named Inventor	Hajime Nakayama
	Group Art Unit	2811
	Examiner Name	D. Kang
	Attorney Docket Number	09792909-4043
Total Number of Pages in This Submission	6	

ENCLOSURES (check all that apply)		
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SIGNATURE OF APPLICANT, ATTORNEY, OR AGENT	
Firm or Individual name	Jeffrey F. Craft, Esq. SONNENSCHNATH & ROSENTHAL
Signature	
Date	JUNE 5, 2001

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I hereby certify that this correspondence is being deposited with the United States Postal Service with sufficient postage as first class mail in an envelope addressed to: Commissioner for Patents, Washington, DC 20231 on this date: June 5, 2001			
Typed or printed name	Kathleen Gaines		
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Docket No. 9792989-24543
(P98,2413)

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PATENT
JUN 13 2001
TC 2800 MAIL ROOM

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re U.S. Patent Application of:)
Hajime Nakayama)
Serial No.: 09/210,540) Examiner: D. Kang
Filed: December 14, 1998) Group Art Unit: 2811
For: SEMICONDUCTOR DEVICE)

8/B (N)
FJONES
6-20-01

PROPOSED AMENENDMENT UNDER 37 C.F.R. § 116

Assistant Commissioner for Patents
Washington, DC 20231

Dear Sir:

In response to the Final Office Action mailed March 5, 2001, please enter and consider the following amendment and remarks. It is believed that the amendment, which merely incorporates the elements of claim 2 into claim 1, will either place the application in condition for allowance or simplify the issues for appeal.

In the claims:

Please amend claim 1 as follows:

1. (amended) A semiconductor device comprising:
a first element formation region in which a device of a first conductivity type is formed;
a second element formation region separated from said first element formation region by an element isolation region and in which a device of a second conductivity type different from said first conductivity type is formed;
a first gate electrode provided on said first element formation region and containing an impurity of the first conductivity type;